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**INTEGRATED CIRCUITS, SILICON MONOLITHIC,  
ADVANCED CMOS DUAL  $\bar{J}$ -K  
POSITIVE EDGE-TRIGGERED FLIP-FLOPS,  
WITH PRESET AND CLEAR,  
BASED ON TYPE 54AC109  
ESCC Detail Specification No. 9203/086**

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**INTEGRATED CIRCUITS, SILICON MONOLITHIC,**

**ADVANCED CMOS DUAL J- $\bar{K}$**

**POSITIVE EDGE-TRIGGERED FLIP-FLOPS,**

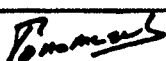

**WITH PRESET AND CLEAR,**


**BASED ON TYPE 54AC109**

**ESA/SCC Detail Specification No. 9203/086**





**space components  
coordination group**

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**DOCUMENTATION CHANGE NOTICE**

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## **APPENDICES (Applicable to specific Manufacturers only)**

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## 1. GENERAL

### 1.1 SCOPE

This specification details the ratings, physical and electrical characteristics, test and inspection data for a silicon, monolithic, advanced CMOS, Dual J-K̄ Positive Edge-Triggered Flip-Flop, with Preset and Clear, having fully buffered outputs, based on Type 54AC109. It shall be read in conjunction with ESA/SCC Generic Specification No. 9000, the requirements of which are supplemented herein.

### 1.2 COMPONENT TYPE VARIANTS

Variants of the basic type integrated circuits specified herein, which are also covered by this specification, are given in Table 1(a).

### 1.3 MAXIMUM RATINGS

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the integrated circuits specified herein, are as scheduled in Table 1(b).

### 1.4 PARAMETER DERATING INFORMATION (FIGURE 1)

Not applicable.

### 1.5 PHYSICAL DIMENSIONS

As per Figure 2.

### 1.6 PIN ASSIGNMENT

As per Figure 3(a).

### 1.7 TRUTH TABLE

As per Figure 3(b).

### 1.8 CIRCUIT SCHEMATIC

As per Figure 3(c).

### 1.9 FUNCTIONAL DIAGRAM

As per Figure 3(d).


### 1.10 HANDLING PRECAUTIONS

These devices are susceptible to damage by electrostatic discharge. Therefore, suitable precautions shall be employed for protection during all phases of manufacture, testing, packaging, shipment and any handling.

These components are Categorised as Class 2 with a Minimum Critical Path Failure Voltage of 4000 Volts.

### 1.11 INPUT AND OUTPUT PROTECTION NETWORKS

Protection networks shall be incorporated into each input and output as shown in Figure 3(e).

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**TABLE 1(a) - TYPE VARIANTS**

VARIANT	CASE	FIGURE	LEAD MATERIAL AND/OR FINISH
01	D.I.L.	2(a)	G4
02	FLAT	2(b)	G4
03	CHIP CARRIER	2(c)	2
04	CHIP CARRIER	2(c)	4

**TABLE 1(b) - MAXIMUM RATINGS**

NO.	CHARACTERISTICS	SYMBOL	MAXIMUM RATINGS	UNITS	REMARKS
1	Supply Voltage	$V_{DD}$	-0.5 to +6.0	V	Note 1
2	Input Voltage	$V_{IN}$	-0.5 to $V_{DD} + 0.5$	V	Notes 1, 2
3	Output Voltage	$V_{OUT}$	-0.5 to $V_{DD} + 0.5$	V	Notes 1, 3
4	Device Dissipation (Continuous)	$P_D$	528	mW	Note 4
5	Supply Current	$I_{DDop}$	96	mA	
6	Operating Temperature Range	$T_{op}$	-55 to +125	°C	$T_{amb}$
7	Storage Temperature Range	$T_{stg}$	-65 to +150	°C	
8	Soldering Temperature For FP and DIP For CCP	$T_{sol}$	+265 +245	°C	Note 5 Note 6

**NOTES**

1. Device is functional for  $3.0V \leq V_{DD} \leq 5.5V$ .
2. Input current limited to  $I_{IC} = \pm 20mA$ .
3. Output current limited to  $I_{OUT} = \pm 50mA$ .
4. The maximum device dissipation is determined by  $I_{DDop} \text{ max. (mA)} \times 5.5V$ .
5. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
6. Duration 5 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.

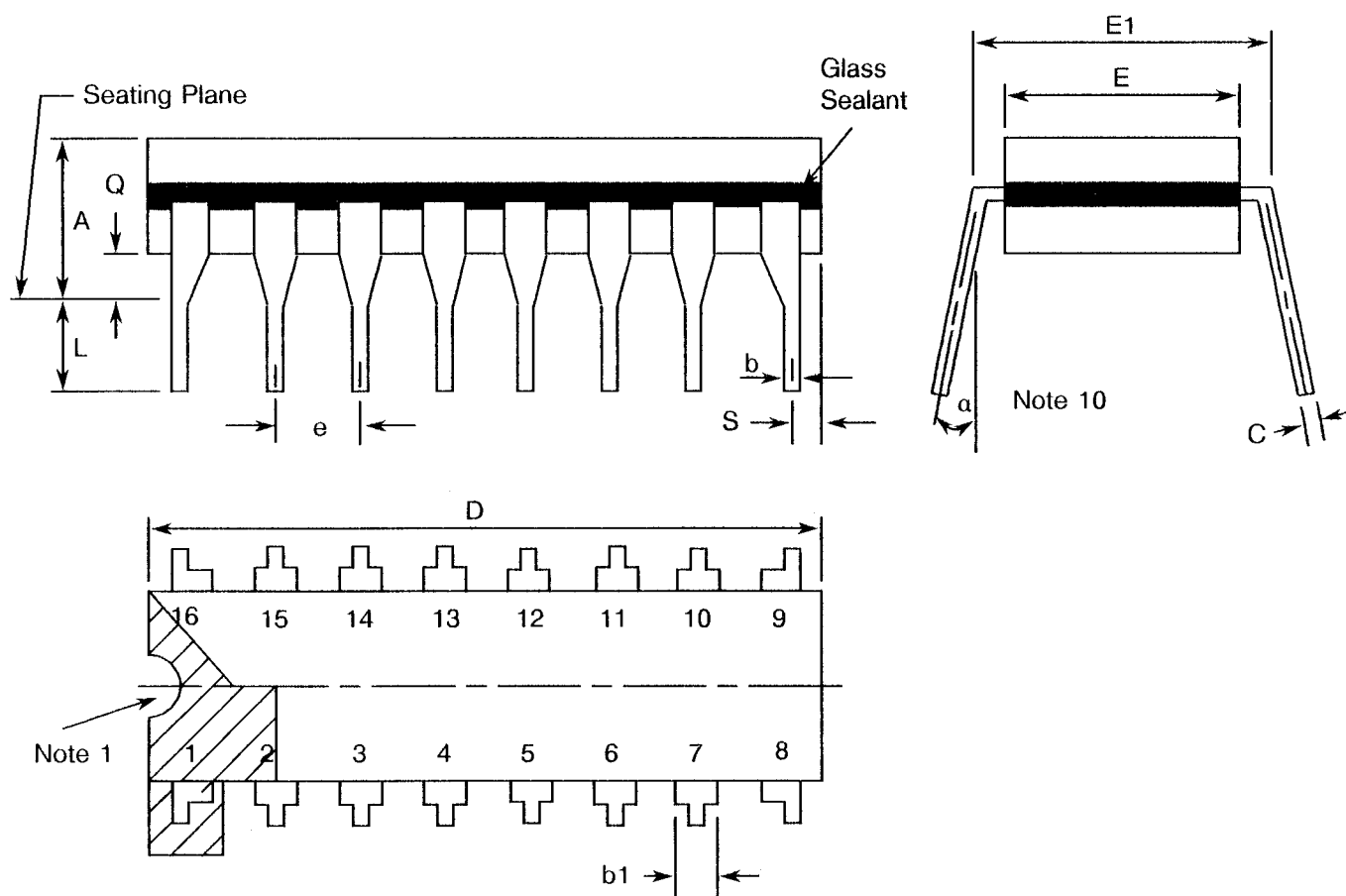
**FIGURE 1 - PARAMETER DERATING INFORMATION**

Not applicable.



## FIGURE 2 - PHYSICAL DIMENSIONS

FIGURE 2(a) - DUAL-IN-LINE PACKAGE, 16-PIN

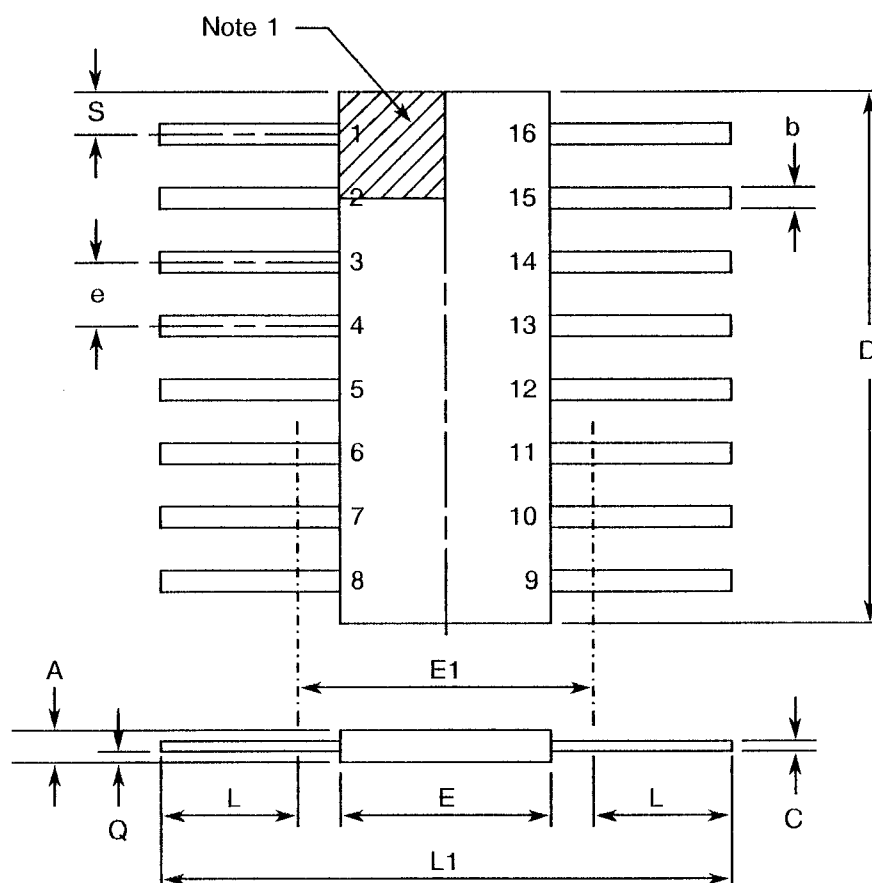


SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	-	5.08	
b	0.35	0.56	8
b1	1.40	1.77	8
C	0.20	0.38	8
D	19.05	19.95	4
E	6.10	7.49	4
E1	7.62 TYPICAL		
e	2.54 TYPICAL		6, 9
L	3.10	4.31	8
Q	0.25	1.02	3
S	0.40	1.10	7
$\alpha$	0°	15°	10

**NOTES:** See Page 10.

**FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)**

**FIGURE 2(b) - FLAT PACKAGE, 16-PIN**

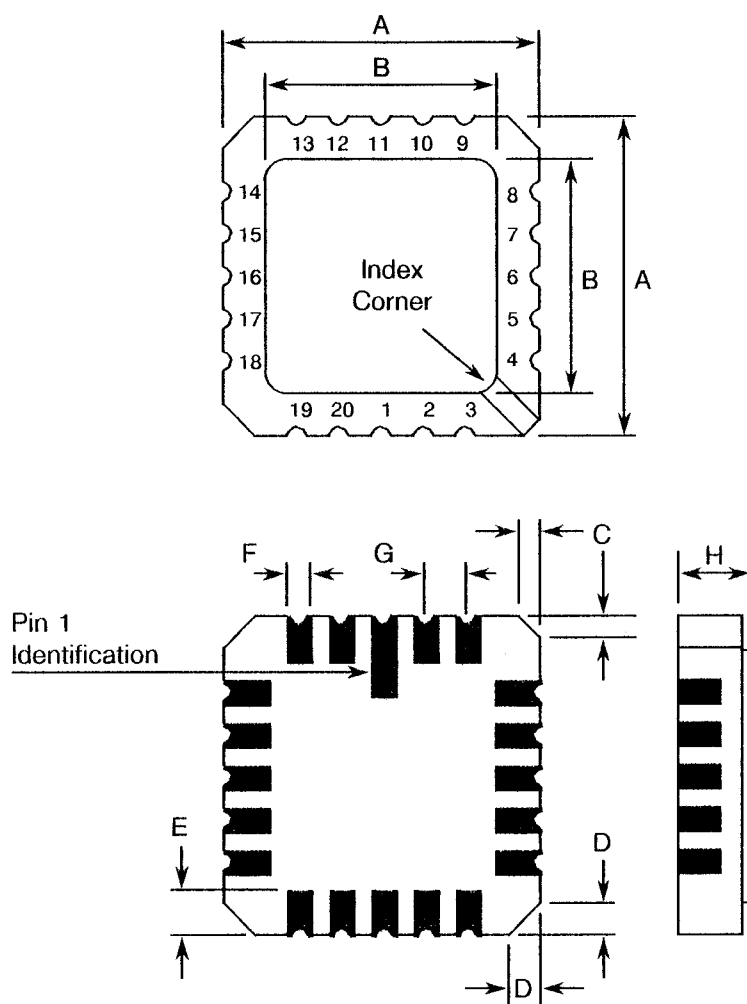


SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	1.52	2.16	
b	0.36	0.56	8
C	0.08	0.17	8
D	9.42	10.16	4
E	5.84	7.24	
E1	7.00 TYPICAL		4
e	1.27 TYPICAL		5, 9
L	5.84	9.14	8
L1	18.93	25.39	
Q	-	1.02	2
S	-	1.40	7

**NOTES:** See Page 10.


**FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)**

**FIGURE 2(c) - SQUARE CHIP CARRIER PACKAGE, 20-TERMINAL**



SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	8.69	9.09	11 12 8 8 5, 9
B	7.80	9.09	
C	0.25	0.51	
D	0.89	1.14	
E	1.14	1.40	
F	0.56	0.71	
G	1.27 TYPICAL		
H	1.63	2.54	

**NOTES:** See Page 10.

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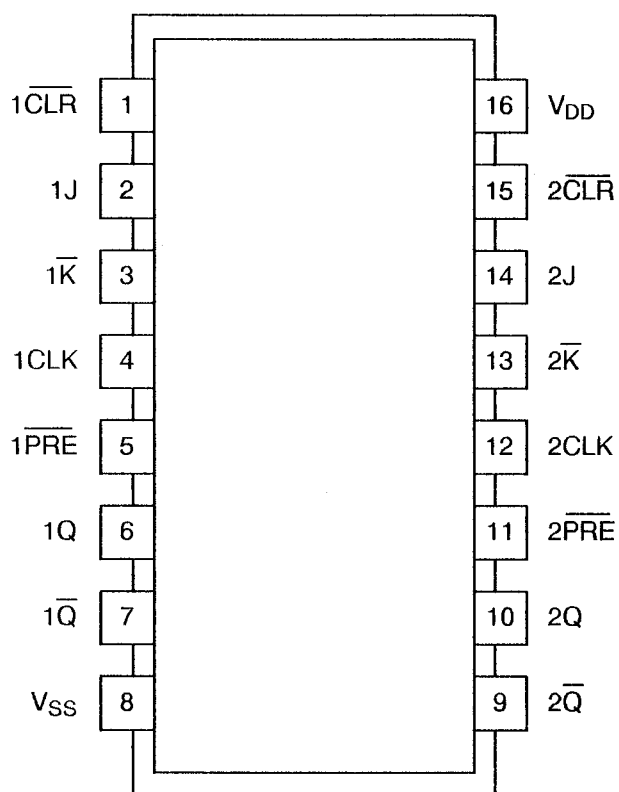
## **FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)**

### **NOTES TO FIGURES 2(a) TO 2(c) INCLUSIVE**

1. Index area: a notch, letter or dot shall be located adjacent to Pin 1 and shall be within the shaded area shown. For chip carrier packages the index shall be as defined in Figure 2(c).
2. Dimension Q shall be measured at the point of exit of the lead from the body.
3. The dimension shall be measured from the seating plane to the base plane.
4. The dimension allows for off-centre lids, meniscus and glass overrun.
5. The true position pin or terminal spacing is 1.27mm between centrelines. Each pin or terminal centreline shall be located within  $\pm 0.13\text{mm}$  of it's true longitudinal position relative to Pin 1 and the highest pin number.
6. The true position pin spacing is 2.54mm between centrelines. Each pin centreline shall be located within  $\pm 0.25\text{mm}$  of it's true longitudinal position relative to Pin 1 and the highest pin number.
7. Applies to all 4 corners.
8. All leads or terminals.
9. 14 spaces for flat and dual-in-line packages.  
16 spaces for chip carrier packages.
10. Lead centreline when  $\alpha$  is  $0^\circ$ .
11. Index corner only - 2 dimensions.
12. 3 non-index corners - 6 dimensions.

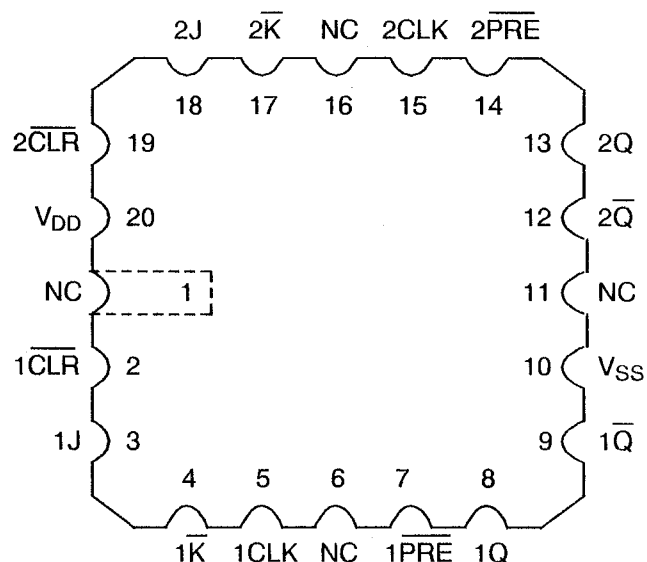
**FIGURE 3(a) - PIN ASSIGNMENT**

DUAL-IN-LINE AND FLAT PACKAGE



TOP VIEW

CHIP CARRIER PACKAGE







TOP VIEW


FLAT PACKAGE AND DUAL-IN-LINE TO CHIP CARRIER PIN ASSIGNMENT

FLAT PACKAGE AND DUAL-IN-LINE PIN OUTS	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
CHIP CARRIER PIN OUTS	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20

**FIGURE 3(b) - TRUTH TABLE (EACH FLIP-FLOP)**

INPUTS					OUTPUTS		FUNCTION
$\overline{\text{PRE}}$	$\overline{\text{CLR}}$	CLK	J	$\overline{\text{K}}$	Q	$\overline{\text{Q}}$	
L	H	X	X	X	H	L	PRESET
H	L	X	X	X	L	H	CLEAR
L	L	X	X	X	H	H	NON STABLE CONFIGURATION (Note 4)
H	H		L	L	L	H	-
H	H		H	L	TOGGLE		-
H	H		L	H	$Q_0$	$\overline{Q}_0$	NO CHANGE
H	H		H	H	H	L	-
H	H	L	X	X	$Q_0$	$\overline{Q}_0$	NO CHANGE

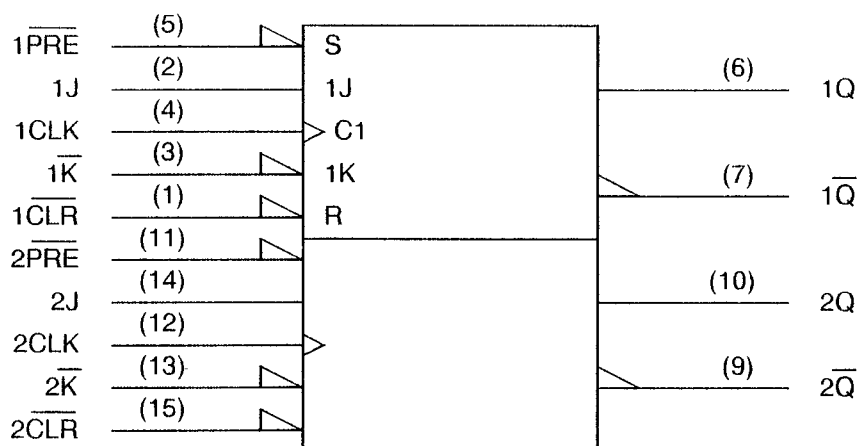
**NOTES**

- Logic Level Definitions: L = Low Level, H = High Level, X = Irrelevant.
-  = Transition, Low to High.
- $Q_0$  or  $\overline{Q}_0$  = The level of  $Q_0$  or  $\overline{Q}_0$  respectively before the indicated steady state input conditions are established.
- This condition is NON-STABLE, i.e. it will not persist when  $\overline{\text{PRE}}$  or  $\overline{\text{CLR}}$  return to their inactive (High) level state.

**FIGURE 3(c) - CIRCUIT SCHEMATIC**

Not applicable.

**FIGURE 3(d) - FUNCTIONAL DIAGRAM**

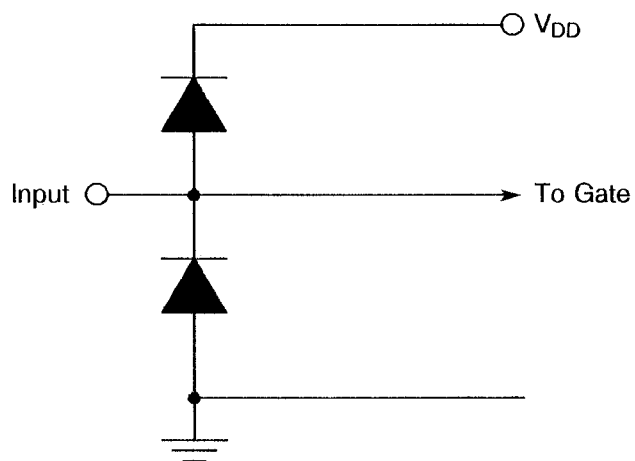


**NOTES**

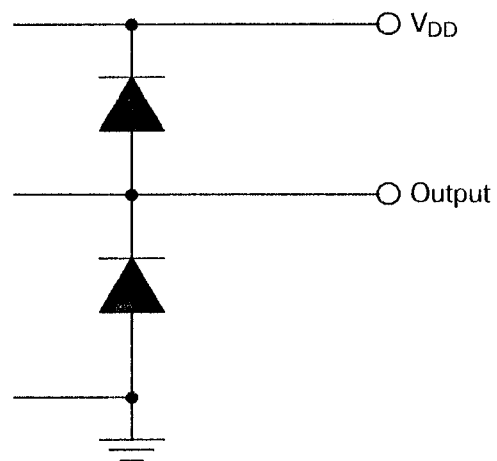
- Pin numbers shown are for DIP and FP.


**FIGURE 3(e) - INPUT AND OUTPUT PROTECTION NETWORKS**

INPUT PROTECTION



OUTPUT PROTECTION



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## 2. APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 9000 for Integrated Circuits.
- (b) MIL-STD-883, Test Methods and Procedures for Micro-electronics.

## 3. TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply. In addition, the following symbols are used:

- $V_{IC}$  = Input Clamp Voltage.
- $I_{IC}$  = Input Clamp Diode Current.
- $V_{OLP}$  = Ground Bounce Outputs Low.
- $V_{OHV}$  = Ground Bounce Outputs High.

## 4. REQUIREMENTS

### 4.1 GENERAL

The complete requirements for procurement of the integrated circuits specified herein are stated in this specification and ESA/SCC Generic Specification No. 9000 for Integrated Circuits. Deviations from the Generic Specification, applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESA/SCC requirements and do not affect the components' reliability, are listed in the appendices attached to this specification.

### 4.2 DEVIATIONS FROM GENERIC SPECIFICATION

#### 4.2.1 Deviations from Special In-process Controls

- (a) Para. 5.2.2, Total Dose Irradiation Testing: Shall be performed during qualification and maintenance of qualification.
- (b) Para. 5.2.2, Total Dose Irradiation Testing: If specified in a Purchase Order, shall be performed during procurement on a lot acceptance basis at the total dose irradiation level specified in the Purchase Order.

#### 4.2.2 Deviations from Final Production Tests (Chart II)

None.


#### 4.2.3 Deviations from Burn-in Tests (Chart III)

None.

#### 4.2.4 Deviations from Qualification Tests (Chart IV)

None.



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#### 4.2.5 Deviations from Lot Acceptance Tests (Chart V)

None.

### 4.3 MECHANICAL REQUIREMENTS

#### 4.3.1 Dimension Check

The dimensions of the integrated circuits specified herein shall be checked. They shall conform to those shown in Figure 2.

#### 4.3.2 Weight

The maximum weight of the integrated circuits specified herein shall be 2.2 grammes for the dual-in-line package, 0.7 grammes for the flat package and 0.6 grammes for the chip carrier package.

### 4.4 MATERIALS AND FINISHES

The materials shall be as specified herein. Where a definite material is not specified, a material which will enable the integrated circuits specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

#### 4.4.1 Case

The case shall be hermetically sealed and have a metal body with hard glass seals or a ceramic body and the lids shall be welded, brazed, preform-soldered or glass frit sealed.

#### 4.4.2 Lead Material and Finish

For dual-in-line and flat packages, the material shall be Type 'G' with Type '4' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. For chip carrier packages the finish shall be Type '2' or Type '4' in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

### 4.5 MARKING



#### 4.5.1 General

The marking of all components delivered to this specification shall be in accordance with the requirements of ESA/SCC Basic Specification No. 21700. Each component shall be marked in respect of:-

- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

#### 4.5.2 Lead Identification

For dual-in-line and flat packages, an index shall be located at the top of the package in the position defined in Note 1 to Figure 2 or, alternatively, a tab may be used to identify Pin No. 1. The pin numbering must be read with the index or tab on the left-hand side. For chip carrier packages, the index shall be as defined by Figure 2(c).

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#### 4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:

920308601BF

Detail Specification Number \_\_\_\_\_  
 Type Variant (see Table 1(a)) \_\_\_\_\_  
 Testing Level (B or C, as applicable) \_\_\_\_\_  
 Total Dose Irradiation Level (if applicable) \_\_\_\_\_

The Total Dose Irradiation Level designation shall be added for those devices for which a sample has been successfully tested to the level in question. For these devices, a code letter shall be added in accordance with the requirements of ESA/SCC Basic Specification No. 22900.

#### 4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESA/SCC Basic Specification No. 21700.

### 4.6 ELECTRICAL MEASUREMENTS

#### 4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured in respect of electrical characteristics are scheduled in Table 2. Unless otherwise specified, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

#### 4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3. The measurements shall be performed at  $T_{amb} = +125 (+0 -5)$  °C and  $-55 (+5 -0)$  °C respectively.

#### 4.6.3 Circuits for Electrical Measurements

Circuits and test sequences for use in performing electrical measurements listed in Tables 2 and 3 of this specification are shown in Figure 4.

### 4.7 BURN-IN TESTS

#### 4.7.1 Parameter Drift Values

The parameter drift values applicable to H.T.R.B. and Power Burn-in are specified in Table 4 of this specification. Unless otherwise stated, measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C. The parameter drift values ( $\Delta$ ) applicable to the parameters scheduled, shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.


For H.T.R.B. Burn-in, the parameter drift values ( $\Delta$ ) shall be applied before the N-Channel (0 hours) and after the P-Channel (144 hours) burn-in.

#### 4.7.2 Conditions for H.T.R.B. and Power Burn-in

The requirements for H.T.R.B. and Power Burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 9000. The conditions for H.T.R.B. and Power Burn-in shall be as specified in Tables 5(a), 5(b) and 5(c) of this specification.

#### 4.7.3 Electrical Circuits for H.T.R.B and Power Burn-in


Circuits for use in performing the H.T.R.B. and Power Burn-in tests are shown in Figures 5(a), 5(b) and 5(c) of this specification.

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**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test 1	-	-	3(b)	Verify Truth Table with Load. $V_{IL} = 0.45V$ , $V_{IH} = 2.5V$ $I_{OL} = 1.0mA$ , $I_{OH} = -1.0mA$ $V_{DD} = 3.0V$ , $V_{SS} = 0V$ $t_r = t_f < 100ns$ $f = 10kHz$ (min) Note 1	-	-	-
2	Functional Test 2	-	-	3(b)	Verify Truth Table with Load. $V_{IL} = 0.6V$ , $V_{IH} = 3.7V$ $I_{OL} = 1.0mA$ , $I_{OH} = -1.0mA$ $V_{DD} = 4.5V$ , $V_{SS} = 0V$ $t_r = t_f < 50ns$ $f = 10kHz$ (min) Note 1	-	-	-
3	Functional Test 3	-	-	3(b)	Verify Truth Table with Load. $V_{IL} = 1.0V$ , $V_{IH} = 4.5V$ $I_{OL} = 1.0mA$ , $I_{OH} = -1.0mA$ $V_{DD} = 5.5V$ , $V_{SS} = 0V$ $t_r = t_f < 50ns$ $f = 10kHz$ (min) Note 1	-	-	-
4 to 5	Quiescent Current	$I_{DD}$	3005	4(a)	$V_{IL} = 0V$ , $V_{IH} = 5.5V$ $V_{DD} = 5.5V$ , $V_{SS} = 0V$ All Outputs Open Note 2 (Pin D/F 16) (Pin C 20)	-	1.0	$\mu A$
6 to 15	Input Current Low Level	$I_{IL}$	3009	4(b)	$V_{IN}$ (Under Test) = 0V $V_{IN}$ (Remaining Inputs) = 5.5V $V_{DD} = 5.5V$ , $V_{SS} = 0V$ (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	-	- 100	nA
16 to 25	Input Current High Level	$I_{IH}$	3010	4(c)	$V_{IN}$ (Under Test) = 5.5V $V_{IN}$ (Remaining Inputs) = 0V $V_{DD} = 5.5V$ , $V_{SS} = 0V$ (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	-	100	nA


**NOTES:** See Page 22.

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**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
26 to 29	Output Voltage Low Level 1	V <sub>OL1</sub>	3007	4(d)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OL</sub> = 50μA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.1	V
30 to 33	Output Voltage Low Level 2	V <sub>OL2</sub>	3007	4(d)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OL</sub> = 50μA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.1	V
34 to 37	Output Voltage Low Level 3	V <sub>OL3</sub>	3007	4(d)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OL</sub> = 50μA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.1	V
38 to 41	Output Voltage Low Level 4	V <sub>OL4</sub>	3007	4(d)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OL</sub> = 12mA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.4	V
42 to 45	Output Voltage Low Level 5	V <sub>OL5</sub>	3007	4(d)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OL</sub> = 24mA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.4	V
46 to 49	Output Voltage Low Level 6	V <sub>OL6</sub>	3007	4(d)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OL</sub> = 24mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.4	V
50 to 53	Output Voltage Low Level 7	V <sub>OL7</sub>	3007	4(d)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OL</sub> = 50mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V Note 3 (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	1.65	V
54 to 57	Output Voltage High Level 1	V <sub>OH1</sub>	3006	4(e)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OH</sub> = - 50μA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	2.9	-	V


**NOTES:** See Page 22.

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**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
58 to 61	Output Voltage High Level 2	V <sub>OH2</sub>	3006	4(e)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OH</sub> = -50μA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	4.4	-	V
62 to 65	Output Voltage High Level 3	V <sub>OH3</sub>	3006	4(e)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OH</sub> = -50μA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	5.4	-	V
66 to 69	Output Voltage High Level 4	V <sub>OH4</sub>	3006	4(e)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OH</sub> = -4.0mA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	2.4	-	V
70 to 73	Output Voltage High Level 5	V <sub>OH5</sub>	3006	4(e)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OH</sub> = -24mA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	3.7	-	V
74 to 77	Output Voltage High Level 6	V <sub>OH6</sub>	3006	4(e)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OH</sub> = -24mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	4.7	-	V
78 to 81	Output Voltage High Level 7	V <sub>OH7</sub>	3006	4(e)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OH</sub> = -50mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V Note 3 (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	3.85	-	V
82 to 91	Input Clamp Voltage (to V <sub>SS</sub> )	V <sub>IC1</sub>	3022	4(f)	I <sub>IN</sub> (Under Test) = -1.0mA V <sub>DD</sub> = Open, V <sub>SS</sub> = 0V All Other Pins Open (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	-0.4	-1.5	V
92 to 101	Input Clamp Voltage (to V <sub>DD</sub> )	V <sub>IC2</sub>	3022	4(f)	I <sub>IN</sub> (Under Test) = 1.0mA V <sub>DD</sub> = 0V, V <sub>SS</sub> = Open All Other Pins Open (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	0.4	1.5	V



**NOTES:** See Page 22.

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**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT						
						MIN	MAX							
102 to 111	Input Capacitance	C <sub>IN</sub>	3012	4(g)	V <sub>IN</sub> (Not Under Test) = 0Vdc V <sub>DD</sub> = V <sub>SS</sub> = 0V Note 4 (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	-	8.0	pF						
112 to 113	Propagation Delay Low to High 1 (CLK to Q̄)	t <sub>PLH1</sub>	3003	4(h)	V <sub>IN</sub> (Under Test) = Pulse Generator V <sub>IN</sub> (Remaining Inputs) = Figure 3(b). V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V Note 5 <table><tr><td><u>Pins D/F</u></td><td><u>Pins C</u></td></tr><tr><td>4 to 7</td><td>5 to 9</td></tr><tr><td>12 to 9</td><td>15 to 12</td></tr></table>	<u>Pins D/F</u>	<u>Pins C</u>	4 to 7	5 to 9	12 to 9	15 to 12	-	10	ns
<u>Pins D/F</u>	<u>Pins C</u>													
4 to 7	5 to 9													
12 to 9	15 to 12													
114 to 115	Propagation Delay High to Low 1 (CLK to Q̄)	t <sub>PHL1</sub>	3003	4(h)	V <sub>IN</sub> (Under Test) = Pulse Generator V <sub>IN</sub> (Remaining Inputs) = Figure 3(b). V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V Note 5 <table><tr><td><u>Pins D/F</u></td><td><u>Pins C</u></td></tr><tr><td>4 to 7</td><td>5 to 9</td></tr><tr><td>12 to 9</td><td>15 to 12</td></tr></table>	<u>Pins D/F</u>	<u>Pins C</u>	4 to 7	5 to 9	12 to 9	15 to 12	-	10	ns
<u>Pins D/F</u>	<u>Pins C</u>													
4 to 7	5 to 9													
12 to 9	15 to 12													
116 to 117	Propagation Delay Low to High 2 (CLR̄ to Q̄)	t <sub>PLH2</sub>	3003	4(h)	V <sub>IN</sub> (Under Test) = Pulse Generator V <sub>IN</sub> (Remaining Inputs) = Figure 3(b). V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V Note 5 <table><tr><td><u>Pins D/F</u></td><td><u>Pins C</u></td></tr><tr><td>1 to 7</td><td>2 to 9</td></tr><tr><td>15 to 9</td><td>19 to 12</td></tr></table>	<u>Pins D/F</u>	<u>Pins C</u>	1 to 7	2 to 9	15 to 9	19 to 12	-	9.0	ns
<u>Pins D/F</u>	<u>Pins C</u>													
1 to 7	2 to 9													
15 to 9	19 to 12													
118 to 119	Propagation Delay High to Low 2 (CLR̄ to Q)	t <sub>PHL2</sub>	3003	4(h)	V <sub>IN</sub> (Under Test) = Pulse Generator V <sub>IN</sub> (Remaining Inputs) = Figure 3(b). V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V Note 5 <table><tr><td><u>Pins D/F</u></td><td><u>Pins C</u></td></tr><tr><td>1 to 6</td><td>2 to 8</td></tr><tr><td>15 to 10</td><td>19 to 13</td></tr></table>	<u>Pins D/F</u>	<u>Pins C</u>	1 to 6	2 to 8	15 to 10	19 to 13	-	9.5	ns
<u>Pins D/F</u>	<u>Pins C</u>													
1 to 6	2 to 8													
15 to 10	19 to 13													



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**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS (CONT'D)**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT						
						MIN	MAX							
120 to 121	Propagation Delay Low to High 3 ( $\overline{\text{PRE}}$ to Q)	$t_{\text{PLH3}}$	3003	4(h)	$V_{\text{IN}}$ (Under Test) = Pulse Generator $V_{\text{IN}}$ (Remaining Inputs) = Figure 3(b). $V_{\text{DD}} = 4.5\text{V}$ , $V_{\text{SS}} = 0\text{V}$ Note 5 <table><tr><td><u>Pins D/F</u></td><td><u>Pins C</u></td></tr><tr><td>5 to 6</td><td>7 to 8</td></tr><tr><td>11 to 10</td><td>14 to 13</td></tr></table>	<u>Pins D/F</u>	<u>Pins C</u>	5 to 6	7 to 8	11 to 10	14 to 13	-	9.0	ns
<u>Pins D/F</u>	<u>Pins C</u>													
5 to 6	7 to 8													
11 to 10	14 to 13													
122 to 123	Propagation Delay High to Low 3 ( $\overline{\text{PRE}}$ to $\overline{\text{Q}}$ )	$t_{\text{PHL3}}$	3003	4(h)	$V_{\text{IN}}$ (Under Test) = Pulse Generator $V_{\text{IN}}$ (Remaining Inputs) = Figure 3(b). $V_{\text{DD}} = 4.5\text{V}$ , $V_{\text{SS}} = 0\text{V}$ Note 5 <table><tr><td><u>Pins D/F</u></td><td><u>Pins C</u></td></tr><tr><td>5 to 7</td><td>7 to 9</td></tr><tr><td>11 to 9</td><td>14 to 12</td></tr></table>	<u>Pins D/F</u>	<u>Pins C</u>	5 to 7	7 to 9	11 to 9	14 to 12	-	9.5	ns
<u>Pins D/F</u>	<u>Pins C</u>													
5 to 7	7 to 9													
11 to 9	14 to 12													
124 to 125	Maximum Clock Frequency	$f_{(\text{CL})}$	-	4(h)	Clock = Pulse Generator $V_{\text{DD}} = 3.0\text{V}$ , $V_{\text{SS}} = 0\text{V}$ Notes 6 and 7 (Pins D/F 4-12) (Pins C 5-15)	110	-	MHz						
126	Ground Bounce Output Low (High to Low)	$V_{\text{OLP(H-L)}}$	-	4(i)	$V_{\text{IN}}(2\overline{\text{PRE}}) = 4.0\text{V}$ $V_{\text{IN}}(2\overline{\text{CLR}}) = 1.0\text{V}$ $V_{\text{IN}}(\text{Remaining Inputs})$ = Pulse Generator $V_{\text{DD}} = 5.5\text{V}$ , $V_{\text{SS}} = 0\text{V}$ Note 8 (Pin D/F 10) (Pin C 13)	-	1.5	V						
127	Ground Bounce Output Low (Low to High)	$V_{\text{OLP(L-H)}}$	-	4(i)	$V_{\text{IN}}(2\overline{\text{PRE}}) = 4.0\text{V}$ $V_{\text{IN}}(2\overline{\text{CLR}}) = 1.0\text{V}$ $V_{\text{IN}}(\text{Remaining Inputs})$ = Pulse Generator $V_{\text{DD}} = 5.5\text{V}$ , $V_{\text{SS}} = 0\text{V}$ Note 8 (Pin D/F 10) (Pin C 13)	-	1.5	V						

**NOTES:** See Page 22.

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**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS (CONT'D)**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
128	Ground Bounce Output High (High to Low)	$V_{OHV(H-L)}$	-	4(i)	$V_{IN}(\overline{2PRE}) = 1.0V$ $V_{IN}(\overline{2CLR}) = 4.0V$ $V_{IN}(\text{Remaining Inputs})$ = Pulse Generator $V_{DD} = 5.5V, V_{SS} = 0V$ Note 8 (Pin D/F 10) (Pin C 13)	-	1.5	V
129	Ground Bounce Output High (Low to High)	$V_{OHV(L-H)}$	-	4(i)	$V_{IN}(\overline{2PRE}) = 1.0V$ $V_{IN}(\overline{2CLR}) = 4.0V$ $V_{IN}(\text{Remaining Inputs})$ = Pulse Generator $V_{DD} = 5.5V, V_{SS} = 0V$ Note 8 (Pin D/F 10) (Pin C 13)	-	1.5	V

**NOTES**

1. Maximum time to output comparator strobe 30 $\mu$ s.
2. Test each pattern of Figure 4(a).
3. No more than one output shall be measured at a time and the duration of the test shall not exceed 2.0ms.
4. Guaranteed but not tested.
5. Measurements shall be performed on a 100% basis go-no-go, with read and record on a sample basis, LTPD7 (32 pieces) after Chart III (Burn-in) Tests.
6. Measurement performed on a sample basis, LTPD 7 or lower (see Annexe I of ESA/SCC 9000).
7. A pulse, having the following conditions, shall be applied to the clock input:  $V_P = 0V$  to  $V_{DD}$  Vdc. Maximum clock frequency  $f_{(CL)}$  requirement is considered met if proper output state changes occur with the pulse repetition rate set to that given in the "Limits" column.
8. Hand test on 5 samples to be performed during Qualification and Extension of Qualification only.




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**TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test 1	-	-	3(b)	Verify Truth Table with Load. $V_{IL} = 0.45V$ , $V_{IH} = 2.5V$ $I_{OL} = 1.0mA$ , $I_{OH} = -1.0mA$ $V_{DD} = 3.0V$ , $V_{SS} = 0V$ $t_r = t_f < 100ns$ $f = 10kHz$ (min) Note 1	-	-	-
2	Functional Test 2	-	-	3(b)	Verify Truth Table with Load. $V_{IL} = 0.6V$ , $V_{IH} = 3.7V$ $I_{OL} = 1.0mA$ , $I_{OH} = -1.0mA$ $V_{DD} = 4.5V$ , $V_{SS} = 0V$ $t_r = t_f < 50ns$ $f = 10kHz$ (min) Note 1	-	-	-
3	Functional Test 3	-	-	3(b)	Verify Truth Table with Load. $V_{IL} = 1.0V$ , $V_{IH} = 4.5V$ $I_{OL} = 1.0mA$ , $I_{OH} = -1.0mA$ $V_{DD} = 5.5V$ , $V_{SS} = 0V$ $t_r = t_f < 50ns$ $f = 10kHz$ (min) Note 1	-	-	-
4 to 5	Quiescent Current	$I_{DD}$	3005	4(a)	$V_{IL} = 0V$ , $V_{IH} = 5.5V$ $V_{DD} = 5.5V$ , $V_{SS} = 0V$ All Outputs Open Note 2 (Pin D/F 16) (Pin C 20)	-	20	$\mu A$
6 to 15	Input Current Low Level	$I_{IL}$	3009	4(b)	$V_{IN}$ (Under Test) = 0V $V_{IN}$ (Remaining Inputs) = 5.5V $V_{DD} = 5.5V$ , $V_{SS} = 0V$ (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	-	- 1.0	$\mu A$
16 to 25	Input Current High Level	$I_{IH}$	3010	4(c)	$V_{IN}$ (Under Test) = 5.5V $V_{IN}$ (Remaining Inputs) = 0V $V_{DD} = 5.5V$ , $V_{SS} = 0V$ (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	-	1.0	$\mu A$


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**TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE (CONT'D)**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
26 to 29	Output Voltage Low Level 1	V <sub>OL1</sub>	3007	4(d)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OL</sub> = 50μA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.1	V
30 to 33	Output Voltage Low Level 2	V <sub>OL2</sub>	3007	4(d)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OL</sub> = 50μA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.1	V
34 to 37	Output Voltage Low Level 3	V <sub>OL3</sub>	3007	4(d)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OL</sub> = 50μA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.1	V
38 to 41	Output Voltage Low Level 4	V <sub>OL4</sub>	3007	4(d)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OL</sub> = 12mA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.5	V
42 to 45	Output Voltage Low Level 5	V <sub>OL5</sub>	3007	4(d)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OL</sub> = 24mA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.5	V
46 to 49	Output Voltage Low Level 6	V <sub>OL6</sub>	3007	4(d)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OL</sub> = 24mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.5	V
50 to 53	Output Voltage Low Level 7	V <sub>OL7</sub>	3007	4(d)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OL</sub> = 50mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V Note 3 (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	1.65	V
54 to 57	Output Voltage High Level 1	V <sub>OH1</sub>	3006	4(e)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OH</sub> = - 50μA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	2.9	-	V


**NOTES:** See Page 22.

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**TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE (CONT'D)**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
58 to 61	Output Voltage High Level 2	V <sub>OH2</sub>	3006	4(e)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OH</sub> = -50μA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	4.4	-	V
62 to 65	Output Voltage High Level 3	V <sub>OH3</sub>	3006	4(e)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OH</sub> = -50μA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	5.4	-	V
66 to 69	Output Voltage High Level 4	V <sub>OH4</sub>	3006	4(e)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OH</sub> = -4.0mA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	2.4	-	V
70 to 73	Output Voltage High Level 5	V <sub>OH5</sub>	3006	4(e)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OH</sub> = -24mA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	3.7	-	V
74 to 77	Output Voltage High Level 6	V <sub>OH6</sub>	3006	4(e)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OH</sub> = -24mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	4.7	-	V
78 to 81	Output Voltage High Level 7	V <sub>OH7</sub>	3006	4(e)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OH</sub> = -50mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V Note 3 (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	3.85	-	V
82 to 91	Input Clamp Voltage (to V <sub>SS</sub> )	V <sub>IC1</sub>	3022	4(f)	I <sub>IN</sub> (Under Test) = -1.0mA V <sub>DD</sub> = Open, V <sub>SS</sub> = 0V All Other Pins Open (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	-0.1	-1.5	V
92 to 101	Input Clamp Voltage (to V <sub>DD</sub> )	V <sub>IC2</sub>	3022	4(f)	I <sub>IN</sub> (Under Test) = 1.0mA V <sub>DD</sub> = 0V, V <sub>SS</sub> = Open All Other Pins Open (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	0.1	1.5	V


**NOTES:** See Page 22.

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**TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test 1	-	-	3(b)	Verify Truth Table with Load. $V_{IL} = 0.45V$ , $V_{IH} = 2.5V$ $I_{OL} = 1.0mA$ , $I_{OH} = -1.0mA$ $V_{DD} = 3.0V$ , $V_{SS} = 0V$ $t_r = t_f < 100ns$ $f = 10kHz$ (min) Note 1	-	-	-
2	Functional Test 2	-	-	3(b)	Verify Truth Table with Load. $V_{IL} = 0.6V$ , $V_{IH} = 3.7V$ $I_{OL} = 1.0mA$ , $I_{OH} = -1.0mA$ $V_{DD} = 4.5V$ , $V_{SS} = 0V$ $t_r = t_f < 50ns$ $f = 10kHz$ (min) Note 1	-	-	-
3	Functional Test 3	-	-	3(b)	Verify Truth Table with Load. $V_{IL} = 1.0V$ , $V_{IH} = 4.5V$ $I_{OL} = 1.0mA$ , $I_{OH} = -1.0mA$ $V_{DD} = 5.5V$ , $V_{SS} = 0V$ $t_r = t_f < 50ns$ $f = 10kHz$ (min) Note 1	-	-	-
4 to 5	Quiescent Current	$I_{DD}$	3005	4(a)	$V_{IL} = 0V$ , $V_{IH} = 5.5V$ $V_{DD} = 5.5V$ , $V_{SS} = 0V$ All Outputs Open Note 2 (Pin D/F 16) (Pin C 20)	-	1.0	$\mu A$
6 to 15	Input Current Low Level	$I_{IL}$	3009	4(b)	$V_{IN}$ (Under Test) = 0V $V_{IN}$ (Remaining Inputs) = 5.5V $V_{DD} = 5.5V$ , $V_{SS} = 0V$ (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	-	- 100	nA
16 to 25	Input Current High Level	$I_{IH}$	3010	4(c)	$V_{IN}$ (Under Test) = 5.5V $V_{IN}$ (Remaining Inputs) = 0V $V_{DD} = 5.5V$ , $V_{SS} = 0V$ (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	-	100	nA


**NOTES:** See Page 22.

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**TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE (CONT'D)**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
26 to 29	Output Voltage Low Level 1	V <sub>OL1</sub>	3007	4(d)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OL</sub> = 50μA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.1	V
30 to 33	Output Voltage Low Level 2	V <sub>OL2</sub>	3007	4(d)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OL</sub> = 50μA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.1	V
34 to 37	Output Voltage Low Level 3	V <sub>OL3</sub>	3007	4(d)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OL</sub> = 50μA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.1	V
38 to 41	Output Voltage Low Level 4	V <sub>OL4</sub>	3007	4(d)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OL</sub> = 12mA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.4	V
42 to 45	Output Voltage Low Level 5	V <sub>OL5</sub>	3007	4(d)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OL</sub> = 24mA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.4	V
46 to 49	Output Voltage Low Level 6	V <sub>OL6</sub>	3007	4(d)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OL</sub> = 24mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	0.4	V
50 to 53	Output Voltage Low Level 7	V <sub>OL7</sub>	3007	4(d)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OL</sub> = 50mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V Note 3 (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	-	1.65	V
54 to 57	Output Voltage High Level 1	V <sub>OH1</sub>	3006	4(e)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OH</sub> = - 50μA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	2.9	-	V

**NOTES:** See Page 22.

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**TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE (CONT'D)**

No.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
58 to 61	Output Voltage High Level 2	V <sub>OH2</sub>	3006	4(e)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OH</sub> = -50μA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	4.4	-	V
62 to 65	Output Voltage High Level 3	V <sub>OH3</sub>	3006	4(e)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OH</sub> = -50μA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	5.4	-	V
66 to 69	Output Voltage High Level 4	V <sub>OH4</sub>	3006	4(e)	V <sub>IL</sub> = 0.9V, V <sub>IH</sub> = 2.1V I <sub>OH</sub> = -4.0mA V <sub>DD</sub> = 3.0V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	2.4	-	V
70 to 73	Output Voltage High Level 5	V <sub>OH5</sub>	3006	4(e)	V <sub>IL</sub> = 1.35V, V <sub>IH</sub> = 3.15V I <sub>OH</sub> = -24mA V <sub>DD</sub> = 4.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	3.7	-	V
74 to 77	Output Voltage High Level 6	V <sub>OH6</sub>	3006	4(e)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OH</sub> = -24mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	4.7	-	V
78 to 81	Output Voltage High Level 7	V <sub>OH7</sub>	3006	4(e)	V <sub>IL</sub> = 1.65V, V <sub>IH</sub> = 3.85V I <sub>OH</sub> = -50mA V <sub>DD</sub> = 5.5V, V <sub>SS</sub> = 0V Note 3 (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	3.85	-	V
82 to 91	Input Clamp Voltage (to V <sub>SS</sub> )	V <sub>IC1</sub>	3022	4(f)	I <sub>IN</sub> (Under Test) = -1.0mA V <sub>DD</sub> = Open, V <sub>SS</sub> = 0V All Other Pins Open (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	-0.1	-1.5	V
92 to 101	Input Clamp Voltage (to V <sub>DD</sub> )	V <sub>IC2</sub>	3022	4(f)	I <sub>IN</sub> (Under Test) = 1.0mA V <sub>DD</sub> = 0V, V <sub>SS</sub> = Open All Other Pins Open (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	0.1	1.5	V

**NOTES:** See Page 22.

# **FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS**

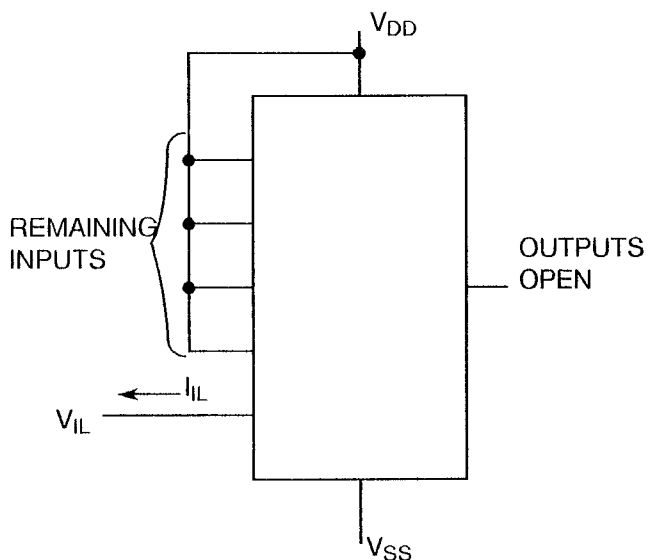
**FIGURE 4 (a) - QUIESCENT CURRENT TEST TABLE**

PATTERN NO.	INPUTS										OUTPUTS				PACKAGE	D.C. SUPPLY	
	1 2	2 3	3 4	4 5	5 7	11 14	12 15	13 17	14 18	15 19	6 8	7 9	9 12	10 13	DIL, FP CCP	8 10	16 20
1	0	1	1	0	1	1	0	1	1	0	OPEN					$V_{SS}$	$V_{DD}$
2	1	1	1	0	0	0	0	1	1	1	OPEN					↓	↓

## **NOTES**

- Figure 4(a) illustrates one series of test patterns. Any other pattern series must be agreed with the Qualifying Space Agency and shall be included as an Appendix.
- Logic Level Definitions: 1 =  $V_{IH}$  =  $V_{DD}$ , 0 =  $V_{IL}$  =  $V_{SS}$ .

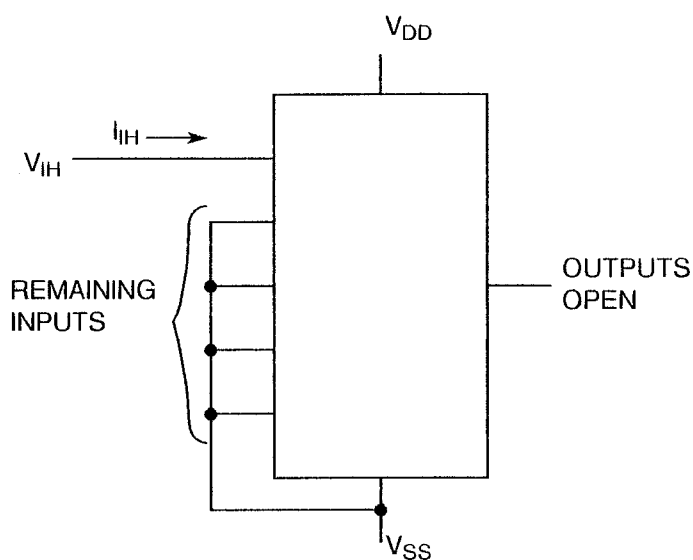
**FIGURE 4(b) - INPUT CURRENT LOW LEVEL**



## **NOTES**

- Each input to be tested separately

**FIGURE 4(c) - INPUT CURRENT HIGH LEVEL**

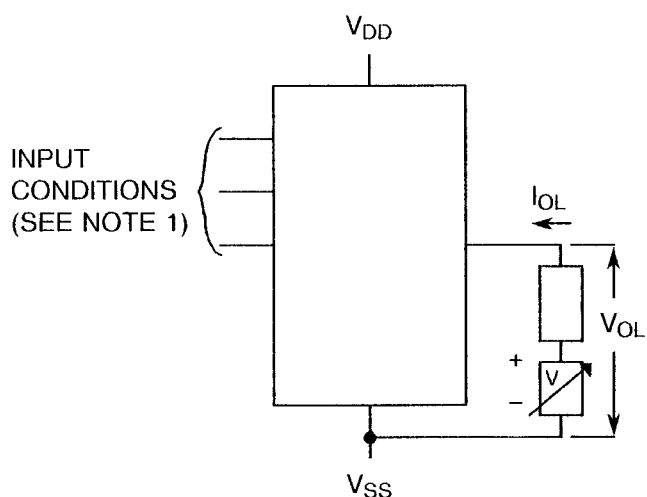


## **NOTES**

- Each input to be tested separately

# **FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)**

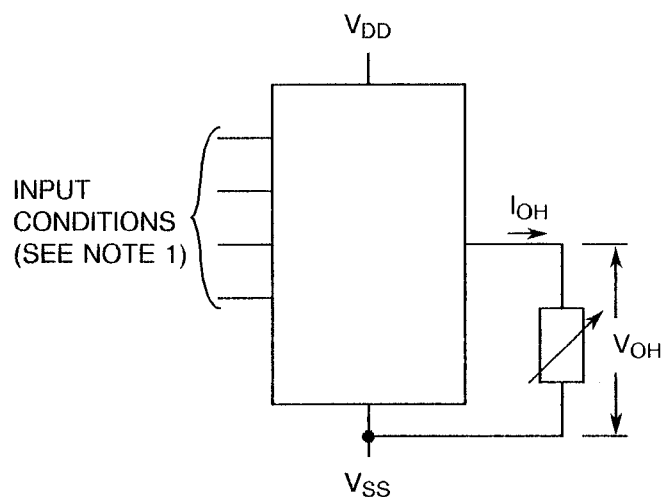
**FIGURE 4(d) - OUTPUT VOLTAGE LOW LEVEL**



## **NOTES**

1.  $V_{IN} = V_{IL} \text{ (max.)}$  and/or  $V_{IH} \text{ (min.)}$  as per Truth Table to give  $V_{OL}$ .
2. Each output to be tested separately.

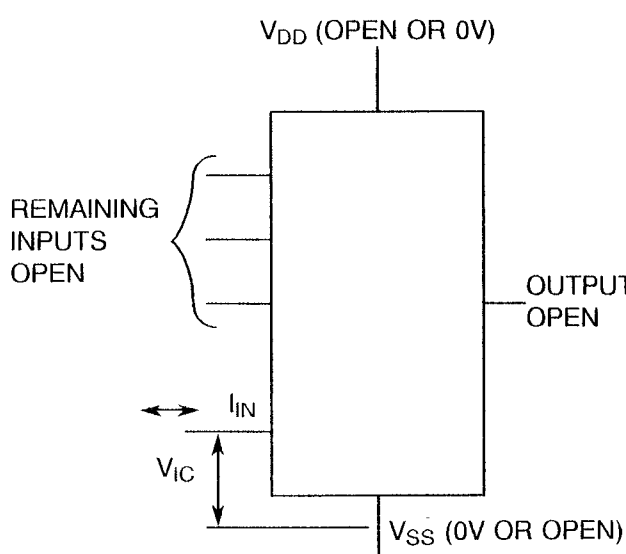
**FIGURE 4(e) - OUTPUT VOLTAGE HIGH LEVEL**



## **NOTES**

1.  $V_{IN} = V_{IL} \text{ (max.)}$  and/or  $V_{IH} \text{ (min.)}$  as per Truth Table to give  $V_{OH}$ .
2. Each output to be tested separately.

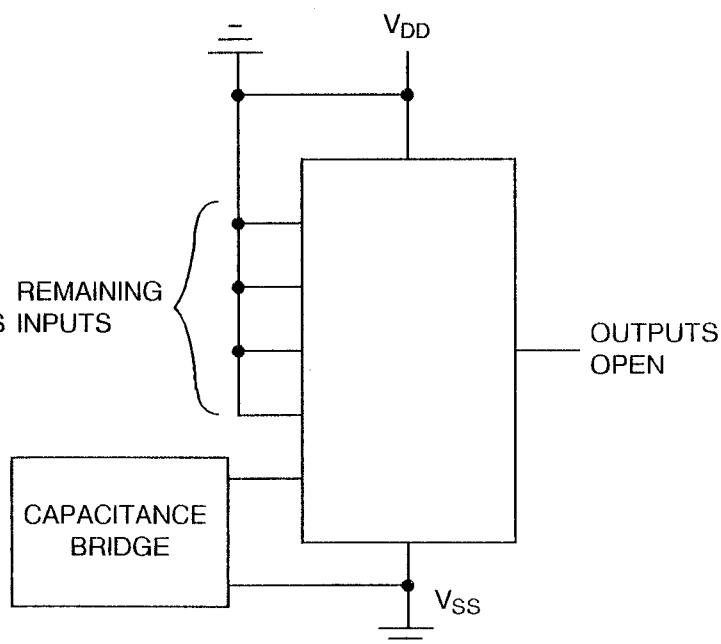
**FIGURE 4(f) - INPUT CLAMP VOLTAGE**



## **NOTES**

1. Each input to be tested separately.

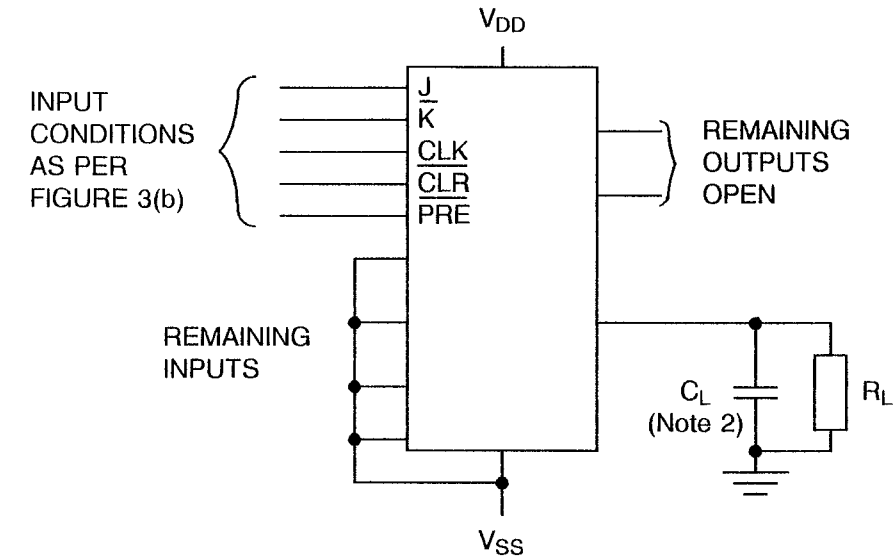
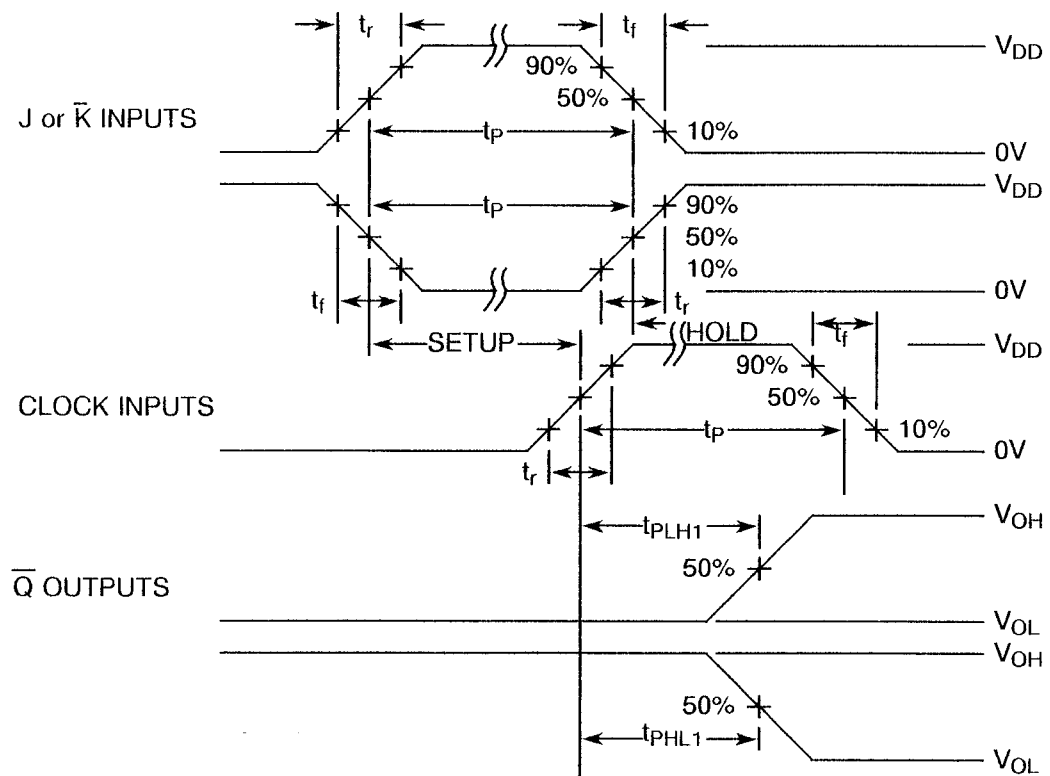
**FIGURE 4(g) - INPUT CAPACITANCE**



## **NOTES**

1. Each input to be tested separately.
2.  $f = 100\text{kHz}$  to  $1\text{MHz}$ .

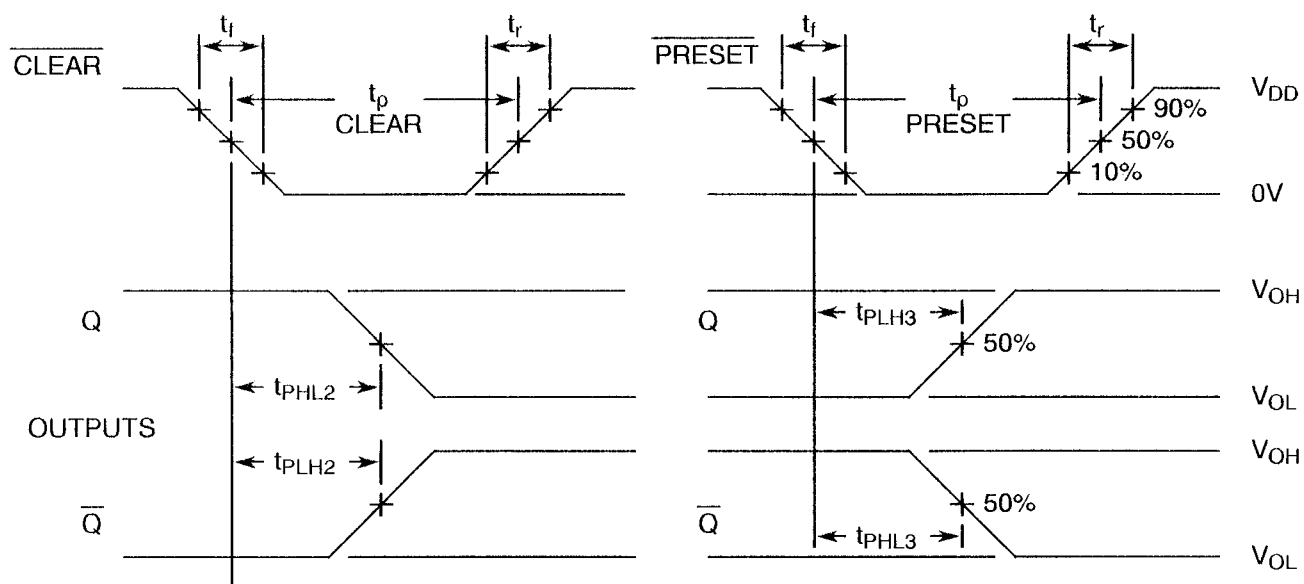


**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(h) - PROPAGATION DELAY****VOLTAGE WAVEFORMS****NOTES**

1. Pulse Generator -  $V_P = 0V$  to  $V_{DD}$ ,  $t_r$  and  $t_f \leq 6ns$ ,  $f = 1.0MHz$  minimum, 50% Duty Cycle,  $Z_{OUT} = 50\Omega$ .
2.  $C_L = 50pF \pm 5\%$  including scope, wiring and stray capacitance without package in test fixture,  $R_L = 500\Omega \pm 5\%$ .

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)**

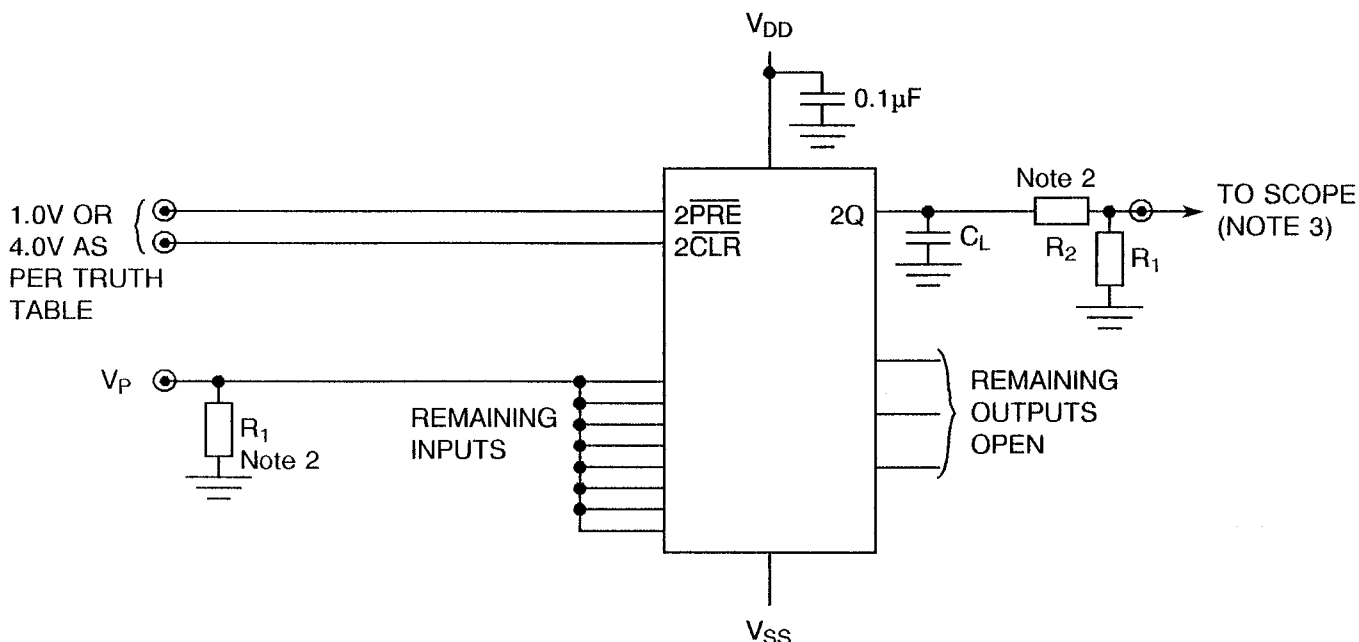
**FIGURE 4(h) - PROPAGATION DELAY (CONTINUED)**



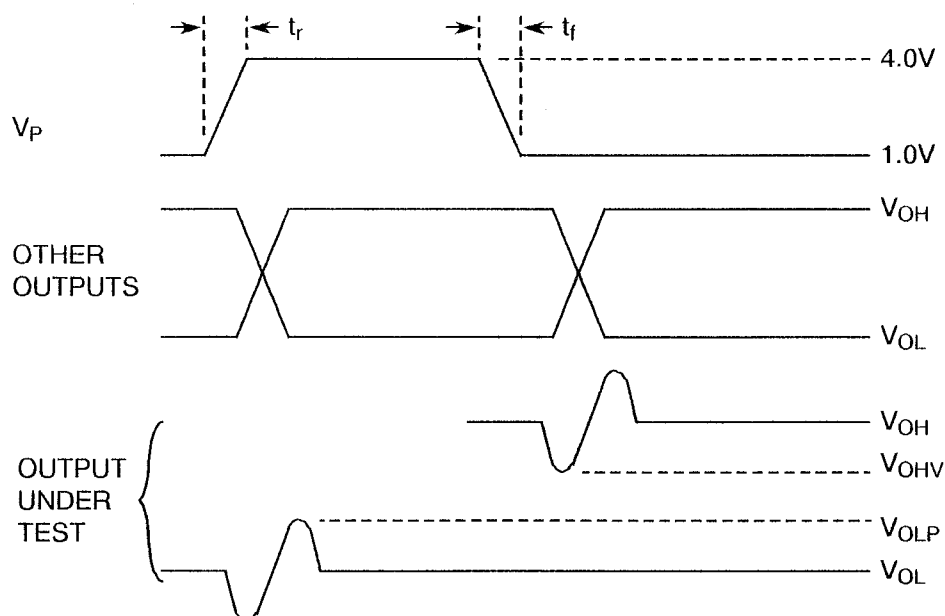
**NOTES:** See Page 31.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)**

**FIGURE 4(i) - GROUND BOUNCE**





**VOLTAGE WAVEFORMS**



**NOTES**

1. Pulse Generator -  $V_P = 1.0V$  to  $4.0V$ ,  $t_r$  and  $t_f \leq 6.0ns$ ,  $f = 1.0MHz$ , 50% Duty Cycle,  $Z_{OUT} = 50\Omega$ .
2.  $C_L = 50pF \pm 5\%$ ,  $R_1 = 51\Omega \pm 5\%$ ,  $R_2 = 450\Omega \pm 5\%$ .
3. Oscilloscope -  $Z_{IN} = 50\Omega$ , Bandwidth  $\geq 1.0GHz$  with memory capability.

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**TABLE 4 - PARAMETER DRIFT VALUES**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS ( $\Delta$ )	UNIT
4 to 5	Quiescent Current	$I_{DD}$	As per Table 2	As per Table 2	$\pm 300$	nA
6 to 15	Input Current Low Level	$I_{IL}$	As per Table 2	As per Table 2	$\pm 20$	nA
16 to 25	Input Current High Level	$I_{IH}$	As per Table 2	As per Table 2	$\pm 20$	nA
46 to 49	Output Voltage Low Level 6	$V_{OL6}$	As per Table 2	As per Table 2	$\pm 0.04$	V
74 to 77	Output Voltage High Level 6	$V_{OH6}$	As per Table 2	As per Table 2	$\pm 0.2$	V

**TABLE 5(a) - CONDITIONS FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, N-CHANNELS**

NO.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	$T_{amb}$	+ 125( + 0-5)	°C
2	Outputs - (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	$V_{OUT}$	Open	-
3	Inputs - (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	$V_{IN}$	$V_{SS}$	V
4	Positive Supply Voltage (Pin D/F 16) (Pin C 20)	$V_{DD}$	5.5( + 0-0.5)	V
5	Negative Supply Voltage (Pin D/F 8) (Pin C 10)	$V_{SS}$	0	V
6	Duration	t	72	Hours

**NOTES**

1. Input Protection Resistor =  $R1 = 1.0k\Omega$ .
2. Output Load =  $R2 = 10k\Omega$ .

**TABLE 5(b) - CONDITIONS FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, P-CHANNELS**

NO.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	$T_{amb}$	+ 125( + 0-5)	°C
2	Outputs - (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	$V_{OUT}$	Open	-
3	Inputs - (Pins D/F 1-2-3-4-5-11-12-13-14-15) (Pins C 2-3-4-5-7-14-15-17-18-19)	$V_{IN}$	$V_{DD}$	V
4	Positive Supply Voltage (Pin D/F 16) (Pin C 20)	$V_{DD}$	5.5( + 0-0.5)	V
5	Negative Supply Voltage (Pin D/F 8) (Pin C 10)	$V_{SS}$	0	V
6	Duration	t	72	Hours

**NOTES**

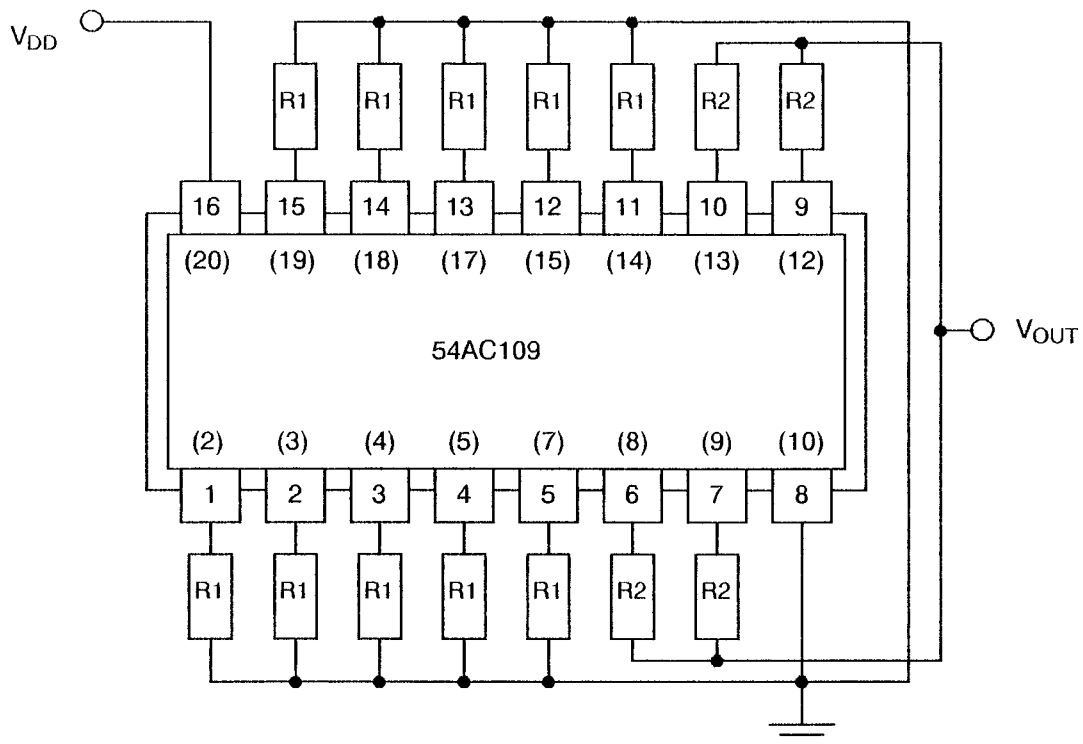
1. Input Protection Resistor =  $R1 = 1.0k\Omega$ .
2. Output Load =  $R2 = 10k\Omega$ .

**TABLE 5(c) - CONDITIONS FOR POWER BURN-IN AND OPERATING LIFE TESTS**

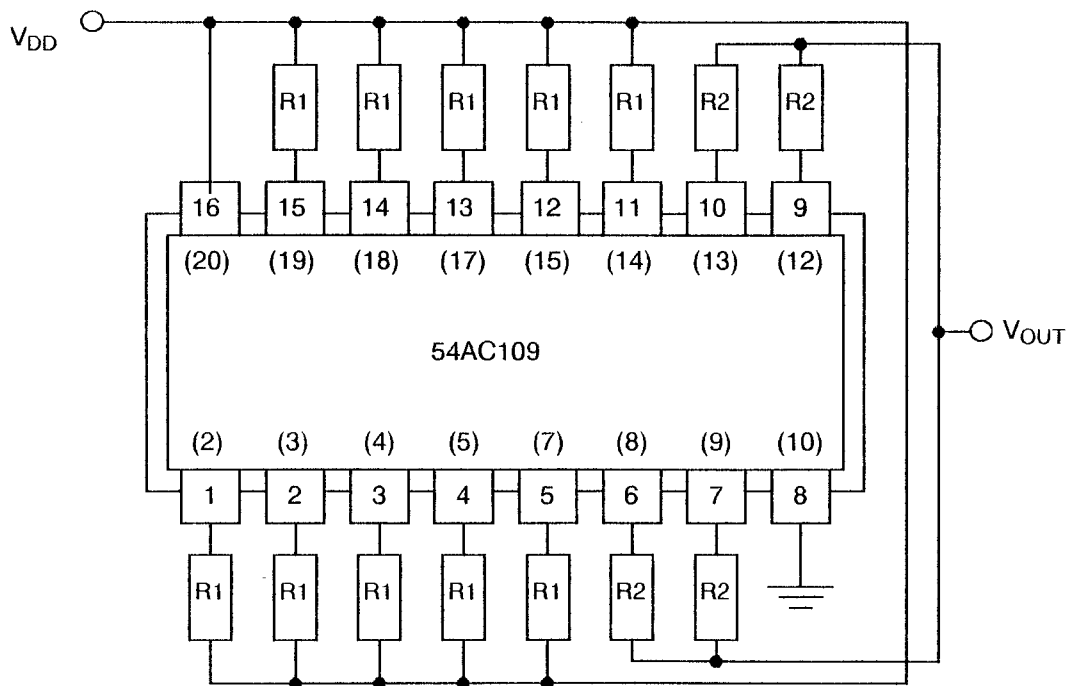
No.	CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT
1	Ambient Temperature	$T_{amb}$	+ 125( + 0 – 5)	°C
2	Outputs - (Pins D/F 6-7-9-10) (Pins C 8-9-12-13)	$V_{OUT}$	$V_{DD}/2$	V
3	Inputs - (Pins D/F 1-2-5-11-14-15) (Pins C 2-3-7-14-18-19)	$V_{IN}$	$V_{DD}$	V
4	Inputs - (Pins D/F 4-12) (Pins C 5-15)	$V_{IN}$	$V_{GEN1}$	Vac
5	Inputs - (Pins D/F 3-13) (Pins C 4-17)	$V_{IN}$	$V_{SS}$	V
6	Pulse Voltage	$V_{GEN}$	0V to $V_{DD}$	Vac
7	Pulse Frequency Square Wave	f	100k $\pm$ 10% 50 $\pm$ 15% Duty Cycle $t_r = t_f < 100ns$	Hz
8	Positive Supply Voltage (Pin D/F 16) (Pin C 20)	$V_{DD}$	5.5( + 0 – 0.5)	V
9	Negative Supply Voltage (Pin D/F 16) (Pin C 20)	$V_{SS}$	0	V

**NOTES**

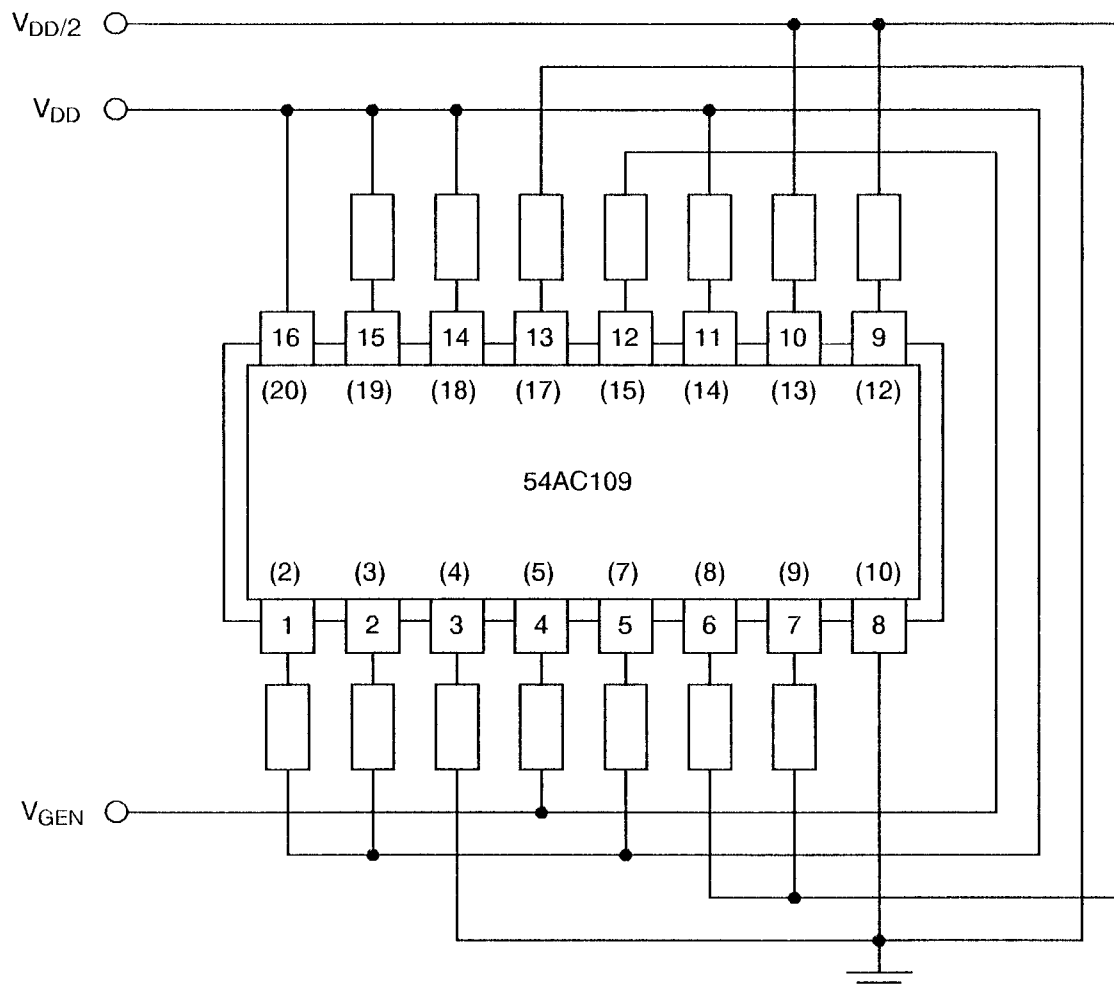
1. Input Protection Resistor = Output Load = 220 $\Omega$ .

**FIGURE 5(a) - ELECTRICAL CIRCUIT FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, N-CHANNELS****NOTES**

1. Pin numbers in parenthesis are for the chip carrier package.


**FIGURE 5(b) - ELECTRICAL CIRCUIT FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, P-CHANNELS****NOTES**

1. Pin numbers in parenthesis are for the chip carrier package.

**FIGURE 5(c) - ELECTRICAL CIRCUIT FOR POWER BURN-IN AND OPERATING LIFE TESTS****NOTES**

1. Pin numbers in parenthesis are for the chip carrier package.



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#### 4.8 ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESA/SCC GENERIC SPECIFICATION NO. 9000)

##### 4.8.1 Electrical Measurements on Completion of Environmental Tests

The parameters to be measured on completion of environmental tests are scheduled in Table 6. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

##### 4.8.2 Electrical Measurements at Intermediate Points during Endurance Tests

The parameters to be measured at intermediate points during endurance tests are as scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

##### 4.8.3 Electrical Measurements on Completion of Endurance Tests

The parameters to be measured on completion of endurance testing are as scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

##### 4.8.4 Conditions for Operating Life Tests

The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 9000. The conditions for operating life testing shall be as specified in Table 5(c) of this specification.

##### 4.8.5 Electrical Circuits for Operating Life Tests

Circuits for use in performing the operating life tests are shown in Figure 5(c) of this specification.

##### 4.8.6 Conditions for High Temperature Storage Test

The requirements for the high temperature storage test are specified in ESA/SCC Generic Specification No. 9000. The temperature to be applied shall be the maximum storage temperature specified in Table 1(b) of this specification.

#### 4.9 TOTAL DOSE IRRADIATION TESTING

##### 4.9.1 Application

If specified in Para. 4.2.1 of this specification, total dose irradiation testing shall be performed in accordance with the requirements of ESA/SCC Basic Specification No. 22900.

##### 4.9.2 Bias Conditions

Continuous bias shall be applied during irradiation testing as shown in Figure 6 of this specification.

##### 4.9.3 Electrical Measurements

The parameters to be measured prior to irradiation exposure are scheduled in Table 2 of this specification. Only devices which meet the requirements of Table 2 shall be included in the test sample.

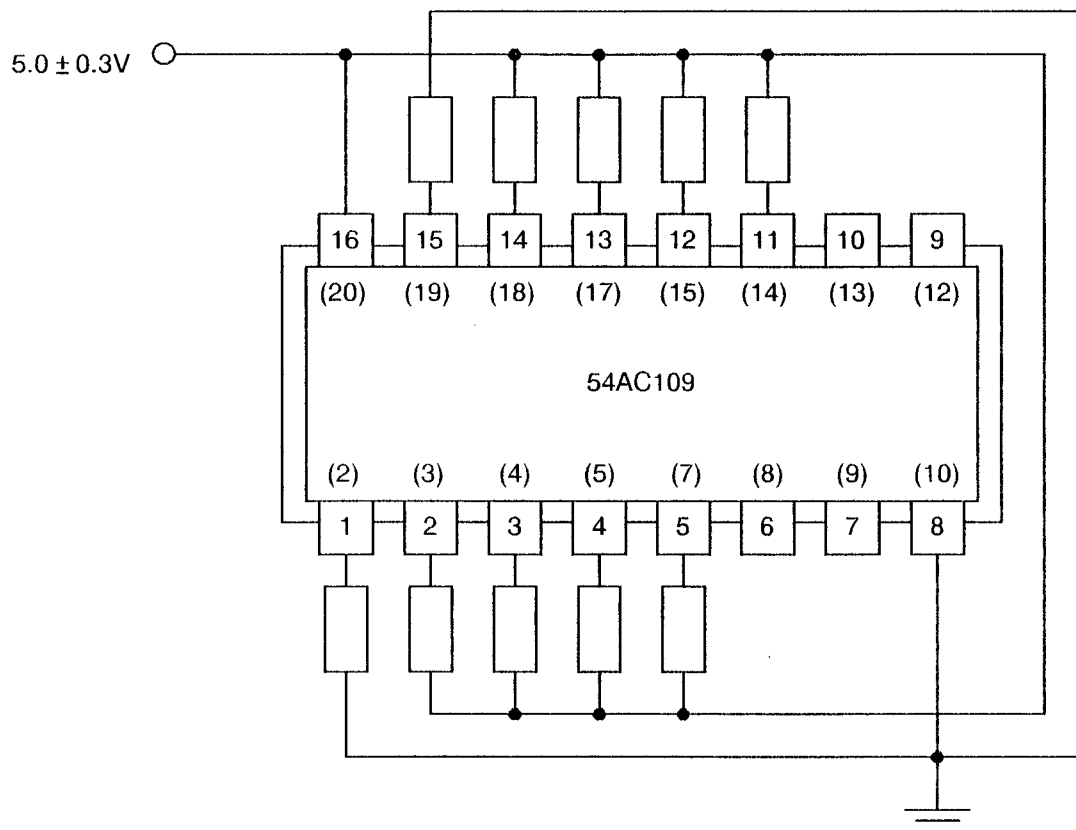
The parameters to be measured during and on completion of irradiation testing are scheduled in Table 7 of this specification.

**TABLE 6 - ELECTRICAL MEASUREMENTS ON COMPLETION OF ENVIRONMENTAL TESTS AND AT INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS ( $\Delta$ ) (NOTE 1)	ABSOLUTE		UNIT
						MIN	MAX	
1	Functional Test 1	-	As per Table 2	As per Table 2	-	-	-	-
2	Functional Test 2	-	As per Table 2	As per Table 2	-	-	-	-
3	Functional Test 3	-	As per Table 2	As per Table 2	-	-	-	-
4 to 5	Quiescent Current	$I_{DD}$	As per Table 2	As per Table 2	$\pm 0.3$	-	1.0	$\mu A$
6 to 15	Input Current Low Level	$I_{IL}$	As per Table 2	As per Table 2	$\pm 20$	-	- 100	nA
16 to 25	Input Current High Level	$I_{IH}$	As per Table 2	As per Table 2	$\pm 20$	-	100	nA
38 to 41	Output Voltage Low Level 4	$V_{OL4}$	As per Table 2	As per Table 2	$\pm 0.04$	-	0.4	V
46 to 49	Output Voltage Low Level 6	$V_{OL6}$	As per Table 2	As per Table 2	$\pm 0.04$	-	0.4	V
66 to 69	Output Voltage High Level 4	$V_{OH4}$	As per Table 2	As per Table 2	$\pm 0.2$	2.4	-	V
74 to 77	Output Voltage High Level 6	$V_{OH6}$	As per Table 2	As per Table 2	$\pm 0.2$	4.7	-	V

**NOTES**


1. The change limits  $\Delta$  are applicable to the Operating Life test only. The change in parameters between initial and end point measurements shall not exceed the limits given. In addition, the absolute limits shall not be exceeded.

**FIGURE 6 - BIAS CONDITIONS FOR IRRADIATION TESTING****NOTES**

1. Pin numbers in parenthesis are for the chip carrier package.
2. Input Protection Resistor = 1.0k $\Omega$ .

**TABLE 7 - ELECTRICAL MEASUREMENTS DURING AND ON COMPLETION OF IRRADIATION TESTING**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS ( $\Delta$ )	ABSOLUTE		UNIT
						MIN	MAX	
1	Functional Test 1	-	As per Table 2	As per Table 2	-	-	-	-
2	Functional Test 2	-	As per Table 2	As per Table 2	-	-	-	-
3	Functional Test 3	-	As per Table 2	As per Table 2	-	-	-	-
4 to 5	Quiescent Current	$I_{DD}$	As per Table 2	As per Table 2	-	-	100	$\mu A$

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**APPENDIX 'A'**

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AGREED DEVIATIONS FOR MOTOROLA (F)

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
Para. 4.2.1(a)	Para. 5.2.2, Total Dose Irradiation Testing: Shall not be performed during qualification and maintenance of qualification.